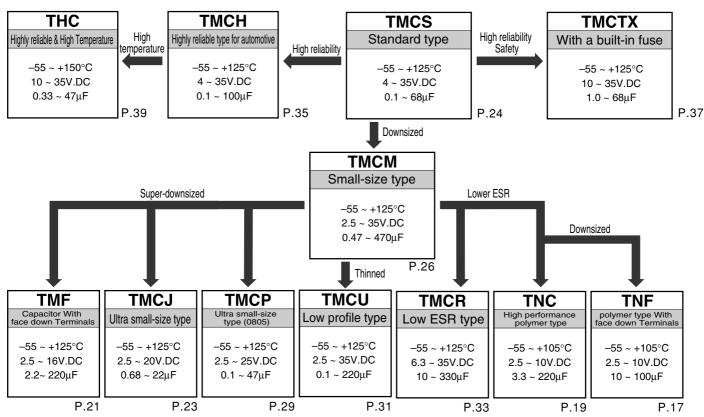
## **Product Table**

## List of tantalum electrolytic capacitor products

Series	Description	Operating temperature range	Standard type	Small-size type	Highly reliable type	Thin type	Low ESR type	Operating voltage V.DC	Capacitance range µF	See page:
TNF	Resin mold chip, polymer type with face down terminals	–55 ~ +105°C		$\bigcirc$			0	2.5 ~ 10	10 ~ 100	17
TNC	Resin mold chip, high performance polymer type	–55 ~ +105°C					0	2.5 ~ 10	3.3 ~ 330	19
TMF	Resin mold chip, capacitor with face down terminals	–55 ~ +125°C		0				2.5 ~ 16	2.2 ~ 220	21
ТМСЈ	Resin mold chip, ultra small-size type (0603)	–55 ~ +125°C		0				2.5 ~ 20	0.68 ~ 22	23
TMCS	Resin mold chip, standard type	–55 ~ +125°C	0					4 ~ 35	0.1 ~ 68	24
тмсм	Resin mold chip, small-size type	–55 ~ +125°C		0				2.5 ~ 35	0.47 ~ 470	26
ТМСР	Resin mold chip, ultra small-size type (0805)	–55 ~ +125°C		0				2.5 ~ 25	0.1 ~ 47	29
тмси	Resin mold chip, low profile type	–55 ~ +125°C				0		2.5 ~ 35	0.1 ~ 220	31
TMCR	Resin mold chip, low ESR type	–55 ~ +125°C					0	6.3 ~ 35	10 ~ 330	33
тмсн	Resin mold chip, highly reliable type	–55 ~ +125°C			0			4 ~ 35	0.1 ~ 100	35
тмстх	Resin mold chip, with a built-in fuse	–55 ~ +125°C			0			10 ~ 35	1.0 ~ 68	37
тнс	Resin mold chip, high relaible, high temperature	–55 ~ +150°C			0			10 ~ 35	0.33 ~ 47	39

## Chip type

VCR cameras, headphones, and other electronic equipment • Cameras • HIC • Automotive electrical equipment
 Personal computers • Cellular communications equipment • DC-DC converters • Others



Planning to change over to Sn100 plating for all series.

## **Precautions in using Tantalum Capacitors**

The major conditions to be considered in relation to the use of the tantalum capacitors are as follows:

- 1) Electrical conditions
- 2) Climatic conditions
- 3) Conditions for mounting on equipment and circuit boards
- 4) Mechanical vibration, shock, and storage conditions

If the tantalum capacitors are used without satisfying any one of these conditions, the probability of short-circuiting, leakage current increase or other problems to occur. To avoid such problems, observe the following precautions when using the tantalum capacitors.

## 1. Operating Voltage

- (1) The voltage derating factor should be as great as possible. Under normal conditions, the operating voltage should be reduced to 50% or less of the rated. It is recommended that the operating voltage be 30% or less of the rated, particularly when the tantalum capacitors are used in a low-impedance circuit (see Figs. 1, 2, and 3).
- (2) For circuits in which a switching, charging, discharging, or other momentary current flows, it is recommended that the operating voltage be 30% or less of the rated, with a resistor connected in series to limit the current to 300 mA or less (see section 4 for details).
- (3) When the tantalum capacitors are to be used at an ambient temperature of higher than 85°C, the recommended operating range shown in Fig. 3 should not be exceeded.

#### • Low-impedance circuits

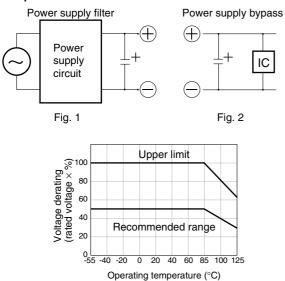


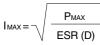
Fig. 3

## 2. Ripple

If an excessive ripple voltage is applied to the tantalum capacitors, their internal temperature rises due to Joule heat, resulting in the detriment of their reliability. The maximum permissible ripple voltage and current are related to the ratings or case size. Please consult us for detail information.

#### 2.1 Ripple Current

The maximum permissible ripple current,  $I_{\mbox{\scriptsize MAX}},$  is calculated as follows:



where:

- IMAX: Maximum permissible capacitor ripple current (Arms). PMAX: Maximum permissible capacitor power loss (W). Varies with the ambient temperature and case size. Calculated according to Table 1.
- ESR (D): Capacitor equivalent series resistance ( $\Omega$ ).

Since the ESR(D) value varies with the ripple frequency, however, the following correction must be made in accordance with the operating frequency (see Table 2 and Fig. 4).

## ESR (D)=K • ESR (120)

K: Coefficient for the operating frequency (Table 2 and Fig. 4).

## ESR (120)=tan $\delta \cdot Xc = \frac{\tan \delta}{2\pi fC}$

where:

- ESR (120): Equivalent series resistance at 120 Hz ( $\Omega$ ).
  - **Xc** : Capacitive reactance at 120 Hz ( $\Omega$ ).
  - C : Electrostatic capacitance at 120 Hz (µF).
  - f : Operating frequency (Hz).

#### Table 1 Maximum permissible power loss values (PMAX) by case size

Ambient temperature			PMAX (W	/)			
(°C)	LM,J	LP,P	LA,UA,A	UB,B	С	E	F
25	0.050	0.064	0.078	0.096	0.100	0.120	0.160
55	0.032	0.045	0.051	0.062	0.065	0.078	0.104
85	0.018	0.023	0.029	0.035	0.037	0.044	0.059

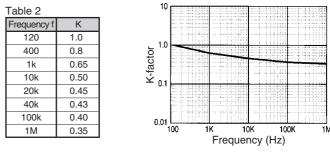
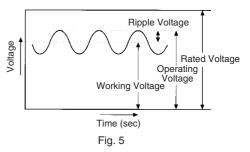


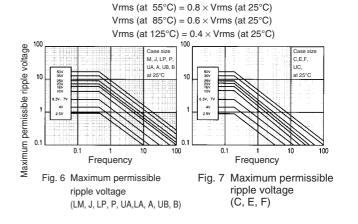
Fig. 4 Correction coefficient (K)

#### 2.2 Ripple Voltage

 The tantalum capacitors must be used in such a conditions that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage (Fig. 5)



- (2) Ensure that an reverse voltage due to superimposed voltages is not applied to the capacitors.
- (3) The maximum permissible ripple voltage varies with the rated voltage. Ensure that ripple voltage does not exceed the values shown in Figs. 6 and 7. If, however, the capacitors are used at a high temperature, the maximum permissible ripple voltage must be calculated as follows:



## 3. Reverse Voltage

- (1) The tantalum capacitors must not be operated and charged in reverse mode. And also the capacitors must not be used in an pure AC circuit.
- The tantalum capacitor dielectric has a rectifying characteristics. (2)Therefore, when a reverse voltage is applied to it, a large current flows even at a low reverse voltage. As a result, it may spontaneously generate heat and lead to shorting.
- Make sure that the polarity and voltage is correct when applying a (3)multimeter or similar testing instrument to the capacitors because a reverse voltage or overvoltage can be accidentally applied.
- (4)When using the capacitors in a circuit in which a reverse voltage is applied, consult your local Hitachi AIC agent. If the application of an reverse voltage is unavoidable, it must not exceed the following values:

At 25°C: 10% of the rated voltage or 1 V, whichever smaller. At 85°C: 5% of the rated voltage or 0.5 V, whichever smaller. Further, the reverse voltage application time must be no longer than 240 hours, with the power supply impedance maintained at  $33\Omega$  or more.

\*These limits are reference value.

## 4. Reliability of Tantalum Capacitors

#### 4.1 General

The failure rate of the tantalum capacitor varies with the derating ratio, ambient temperature, circuit resistance, circuit application, etc. Therefore, when proper selections are made so as to afford additional margins, higher reliabilities can be derived from the tantalum capacitors. Some examples of actual failure rates are presented below for your reference.

### 4.2 Failure Rate Calculation Formula

The tantalum capacitors are designed to work at their basic failure rates shown in Table 3 that prevail when the rated voltage is applied for 1000 hours at 85°C.

Table 3	Basic	failure	rate
---------	-------	---------	------

Туре	Classification	Basic failure rate
TMCR	Low ESR type	
TMF	Face down terminals	
TMCJ	Ultra small-size type (0603)	
TMCP	Ultra small-size type (0805)	1%/1000hrs
TMCU	Low profile type	
TMCM	Small type	
TMCS	Standard type	
TMCTX	Fuse-incorporated type	
TMCH	High-reliability type	0.5%/1000hrs
TNC	High performance polymer type	1%/1000hrs

A capacitor failure rate can be calculated from the formula shown below. Note that a capacitor failure rate can be lowered by giving margins to the circuit temperature, applied voltage ratio (derating factor), and circuit resistance selected for the basic failure rate.

#### Failure rate calculation formula

 $\lambda$  use =  $\lambda$  85  $\times$  K<sub>V</sub> $\times$  K<sub>R</sub>

- $\lambda$  use: Estimated capacitor failure rate under the operating conditions.
- λ 85: Basic failure rate (Table 3)
- Kv: Failure rate correction coefficient by the ambient temperature and derating factor.
- Failure rate correction coefficient by the circuit resistance, K<sub>R</sub>: which is the series-connected resistance divided by the voltage applied to the capacitor. This resistance is connected in series when the power supply side is viewed from the capacitor side. The  $K_V$  and  $K_B$  values must be determined according to Figs. 8 and 9.

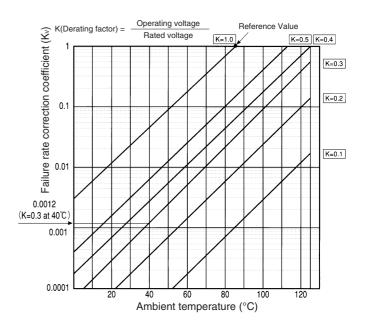


Fig. 8 Ambient temperature and derating-dependent failure rate correction coefficient (Kv)

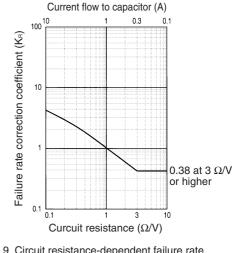


Fig. 9 Circuit resistance-dependent failure rate correction coefficient (KR)

## 4.3 Example of Capacitor Failure Rate Calculation Operating conditions

Туре:	TMCM type
Rating:	10 V, 10 µF (B case)
Operating temperature:	40°C
Derating factor:	0.3 [K=operating voltage / rated
	voltage=3 V/10 V=0.3]
Circuit resistance:	3Ω / V
λ85:	1%/1000 hours (from Table 3)
Kv:	0.0012 (from Fig. 8)
K <sub>B</sub> :	0.38 (from Fig. 9)

λuse=λ85×Kv×KR=1%/1000h×0.0012×0.38

=1×10<sup>-5</sup>×0.0012×0.38

=4.56×10 <sup>-9</sup>	l	Estimated failure rate
=0.000456%/1000h	ſ	Estimated failure rate
=4.56Fit		

## 5. Mounting Precautions

## 5.1 Limit Pressure on Capacitor Installation with Mounter

Pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or the like (maximum permitted pressurization time: 5 seconds). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and/or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

#### 5.2 Flux Selection

- (1) Select a flux that contains a minimum of chlorine and amine.
- (2) After flux use, the chlorine and amine in the flux remain must be removed.

#### 5.3 Recommended Soldering Pattern Dimensions

The recommended chip soldering pattern dimensions are as shown in Table 4 and Fig. 10. Note, however, that they are affected by such factors as reflow conditions, solder type, and circuit board size.

If the pattern area is significantly larger than the capacitor terminal area, the capacitor in place may be displaced when the solder melts.

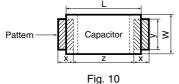


Table 4 Recommended soldering pattern dimensions (mm)

Dimensions	Capaci	tor size	Patt	Pattern dimensions							
Case	L	W	х	у	Z						
LM	1.6	0.8	0.5 <sup>MIN</sup>	0.65 <sup>MIN</sup>	0.65 <sup>max</sup>						
J	1.6	0.8	0.9	1.0	0.7						
LP	2.0	1.25	0.5 <sup>MIN</sup>	0.8 <sup>MIN</sup>	1.05 <sup>MAX</sup>						
Р	2.0	1.25	1.2	1.1	0.8						
LA	3.2	1.6	0.8 <sup>MIN</sup>	1.2 <sup>MIN</sup>	1.65 <sup>MAX</sup>						
LA,UA,A	3.2	1.6	1.6	1.2	1.2						
UB,B	3.5	2.8	1.6	2.2	1.4						
С	5.8	3.2	2.3	2.4	2.4						
E	7.3	4.3	2.3	2.6	3.8						
F	7.3	5.8	2.3	3.8	3.8						

#### 5.4 Chip Soldering Temperature and Time

For the capacitor body, the chip soldering temperature and time must be as shown below.

Reflow soldering (infrared, hot air, hot plate)
 Capacitor body temperature: 260°C or lower(TNC:240°C or lower)
 Time: 10 sec. max.

Permitted temperature/time range: See Fig. 11.

NOTE 1: When upward heating is provided by infrared, the capacitor

body temperature rises above the circuit board surface temperature.

When a high-power hot blast stove or the like is used, a sudden temperature rise occurs.

Therefore, a 130-160°C, 1-minute preheating zone should be provided to ensure that the difference from the reflow maximum temperature is not greater than 100°C (see Fig. 12).

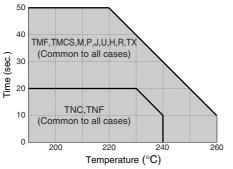
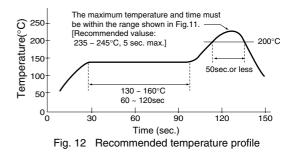


Fig. 11 Reflow soldering permitted temperature / time range



 (2)
 Flow soldering (not available for TNC type)

 Solder bath temperature:
 260°C or lower

 Time:
 LM, J, LP, P, UA, LA,A, UB, or B case, 10

 sec max.
 C, E, F case, 5 sec max.

Permitted temperature and time range: See Fig. 13.

NOTE 1: To avoid sudden heating, conduct preheating. 130-160°C, 1minute preheating zone should be provided (see Fig. 14).

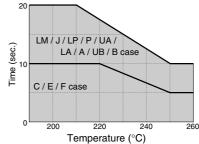
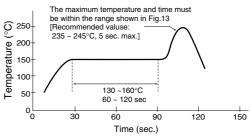


Fig. 13 Flow soldering permitted temperature / time range



#### Fig. 14 Recommended temperature profile Soldering with a soldering iron

The use of a soldering iron should be avoided wherever possible. If it is unavoidable, follow the instructions set forth in Table 5. The time of soldering with an iron should be one.



(3)

Туре	TMCR,TMCS,TMCM,TMCP,TMCJ,TMCU,TMCH	TMCTX *
Soldering-iron tip temperature	350°Cmax	290°С мах
Time	3 SEC MAX	3 Sec MAX
Soldering-iron power	30 W max	30 W max

\*If a soldering iron is used at a high temperature for the TMCTX type which incorporates a thermal fuse, the fuse opens. Due care must be used to avoid such a trouble.

 $\ast lf$  a soldering iron needs to be used for TMF and/or TNC type, please contact us for information.

#### (4) Repetition of soldering

The soldering conditions for soldering operations (1) through (3) above are established on the presumption that only one type of soldering operation is conducted.

When repeating a reflow soldering or a combined flow-and-reflow soldering operation, comply with the following conditions:

- Once the capacitor is mounted, it must not be removed for reuse.
- ii) Any type of soldering operation may be performed to the capacitor only twice.
- iii) The second performance of a type of soldering operation must not be initiated until a 2-hour or longer heat dissipation period has elapsed after completion of the first performance.
- iv) Cleaning must be conducted upon completion of the second performance.

 $\ast Soldering conditions (temperature, time) of Sn 100 terminal products are same as the above.$ 

## 5.5 Cleaning after Mounting

The following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.

- Halogen organic solvent (HCFC225, etc.)
- Alcoholic solvent (IPA, ethanol, etc.)
- · Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50°C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm3, at a temperature of not higher than 40°C, and for a time of 5 minutes or shorter.

NOTE 1: Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or

the like or will not get rubbed by a stiff brush or the like. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur.

NOTE 2: When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout.

## 6. Long-term Stock

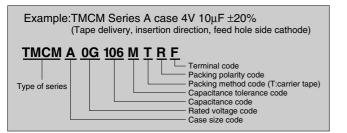
The capacitors which has been storaged for more than 1 years, please contact us before use.

## 7. Others

- (1) For further details, refer to EIAJ RCR-2368B, Precautions and Guidelines for Using Electronic Device Tantalum Capacitors.
- If you have any questions, feel free to contact your local Hitachi AIC agent.

## TAPING AND TERMINAL PLATING SPECIFICATION FOR TMC TYPE CAPACITORS (INCLUDING TMF AND TNC TYPES)

## 1. Product Symbol



### 2. Tape Materials

Transparent or half-transparent plastic covering tape is stuck by heat press.

#### 3. Tape Size

See Fig. 1 and Table 1.

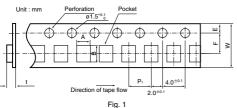
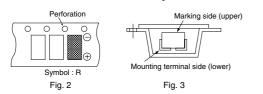


Table 1								(Unit : mm)
Capacitor dimensions	A <sup>±0.1</sup>	B <sup>±0.1</sup>	₩±0.1	F <sup>±0.1</sup>	E <sup>±0.1</sup>	P1 <sup>±0.1</sup>	t <sup>MAX</sup>	Quantity per reel
Р	1.5	2.2	8.0	3.5	1.75	4.0	1.6	3000pcs
UA	1.9	3.5	8.0	3.5	1.75	4.0	1.7	3000pcs
UB	3.1	3.9	8.0	3.5	1.75	4.0	1.7	3000pcs
A	1.9	3.5	8.0	3.5	1.75	4.0	2.5	2000pcs
В	3.1	3.9	8.0	3.5	1.75	4.0	2.5	2000pcs
С	3.7	6.3	12.0	5.5	1.75	8.0	3.0	500pcs
E	4.8	7.7	12.0	5.5	1.75	8.0	3.4	500pcs
F	6.3	7.5	12.0	5.5	1.75	8.0	4.1	500pcs
LM,J	1.0±0.2	1.8±0.2	8.0	3.5	1.75	4.0	1.3	4000pcs
LP	1.5	2.3	8.0	3.5	1.75	4.0	1.5	3000pcs
LA	1.9	3.5	8.0	3.5	1.75	4.0	1.5	3000pcs

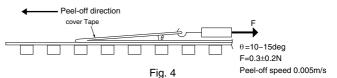
## 4. Inserting Direction

Capacitors are packed with their cathodes on perforation side and with their electrodes faced with the bottoms of the pockets. (See Fig. 3.) Inserting direction



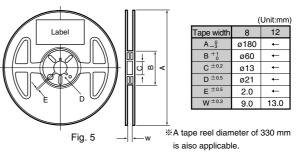
## 5. Adhesion Strength of Cover at Peeling off

When cover tape is peeled off in such manner as Fig. 4 adhesion strength F must be with the range of 0.3±0.2N



### 6. Reel Drawings and Dimensions

As indicated in Fig. 5.



Quantity Packed in Reel and Description

The standard number of capacitors to be accommodated by one reel is as indicated in Table 1.

One side surface of a reel is basically marked with the following items of information.

- (1) Name of capacitor or product identification
- (2) Rated voltage
- (3) Capacitance value
- (4) Capacitance tolerance value
- (5) Quantity
- (6) Lot number for production month / year
- Manufacturer's name or symbol.

#### 8. Part Number Discrimination of terminal plating

No.	Part Number Descrimation	Plating Materials
1		Sn100

\*As regards TNC, TMF and TMCJ types, their terminals are plated only with Sn100.

### 9. Packing and Storage

The capacitors are packed in such a manner that they will not possibly be damaged during transit or storage. As far as they are stored at normal temperature with normal humidity (5 to 35°C, below 75% RH), they are warranted for a period of 1 years from the date of manufacture. TNC series are moisture sensitive. The storage condition recommends JEDEC level 4. The maximum storage is within 1 year. Once Dry Pak is opend parts must be stored at less than 60%RH and 5~30°C and must be Reflow Soldered within 72 hour.

Please pay attention, because a soldering faulty sometimes occurs, in the case that it came off an above strage carlition.

#### 10. Other Specification

The JIS C 0806 Standard, EIAJ EXT-7001 Standard, and relevant agreements are complied with.

## Hitachi AIC Inc.

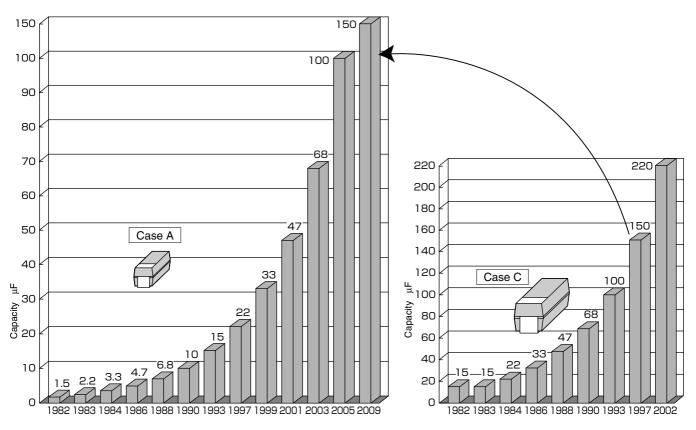
## About downsizing (upgrading)

To meet the recent needs for electronic products smaller in size and lighter in weight, chip type tantalum capacitor manufacturers have been downsized their products by various methods. Of these methods, the method of ensuring a required capacity by thinning the dielectric film greatly reduces the withstand voltage characteristics. The most common method is therefore by using fine tantalum powder to enlarge the surface area of the anode per unit area.

The TMC type has been enlarged in capacity and reduced in size by taking full advantage of fine powder (hereinafter referred to as "high-CV powder"). In recent years, however, technical advances have been remarkable in downsizing and capacity expansion in the industry of multilayer ceramic capacitors. The advantage of TMCs is therefore being challenged. To keep the advantage in competing with ceramic capacitors today, it is imperative to use high-CV powder to upgrade the TMCs.

Hitachi AIC is planning to make yet another family of products.

- (1) Development of products with a larger capacity than the TMCM type
- (2) Development of products with a larger capacity than the TMCP type (0805 inch)
- (3) Development of products with a larger capacity than the TMCU type (thin type, a low-height version of the TMCM type).
- (4) Development of products TMCJ type (0603 inch)
- (5) Development of products Niobium solid Electrolytic Capacitors.
- (6) Development of products with a larger capacity than the TMF type (Face down terminals type).



History of capacity expansion in 6.3-V(7V) models

## Pb free chip tantalum Capacitor (TMC serise)

## •Tin-based Solder for Terminal Plating – Heat-resistant at up to 260°C

#### Lead alloy solder mounting

No need to change existing mounting conditions (for conventional – with lead – production lines)

#### Lead-free solder mounting

For lead-free solder of any base materials (For lead-free production lines)

Hitachi AIC has developed a tantalum capacitor containing no lead at the terminal, which went into mass production in April 2001.

Lead alloy has long been used in electrical and electronic equipment for solderings. Lead is, however, known to be harmful. The European Union has announced that it would ban the use of lead and other hazardous substances from 2006.

In the interest of preserving the global environment, Hitachi AIC has been studying a way to eliminate the use of lead in terminal plating.

The new plating method is based on tin, the main ingredient in joint solder. It can therefore be used in both lead alloy and lead-free soldering.

We ensure this product's high degree of heat-resistance (260°C ; up to 10 seconds) to provide strong support in the move to lead-free production lines.

## Specifications Table

	[		Т	NF			-	TNC				TMF					ТМС	;J			TMC	CS		Test conditions JIS	C5101-1:1998
[	Specifications Table	-55℃~	-+10	)5℃		-55	5℃~+1	05℃		-55	°C ~-	+125°C	;		-55	5°C~-	⊦125°C	)	-55	5℃~	+125℃	2			
	Rated voltage	DC2.5~	~10	V		DC	2.5~10	V		DC	2.5~	-16V			DC	2.5~	20V		DC	4~3	5V			85C	
	Surge voltage	DC3~	13V			DC	3∼13\	/		DC	3.2~	-20V			DC	3.2~	26V		DC	;5~4	5V			85C	
2	Derated voltage	DC1.6~	~6.3	3V		DC	c1.6~6.	3V (10	5℃)	DC	1.6~	-10V			DC	21.6~	13V		DC	2.5~	-22V			125°C (TNC:105°C	, THC:150℃)
	Capacitance	10~10	0 μ I	F		3.3	بر 330~	٤F		2.2~220 μ F				0.68~22 μ F					~68	μF					
A I	Capacitance tolerance	±20%				±20%									±20%					10%	or 209	6		Paragraph 4.7	7, 120 Hz
_	Leakage current	e Refer to standard product table			fer to st oduct ta			whichever is larger					Refer to standard product table					0.01CV or $0.5 \mu$ A, whichever is larger or less.				Paragraph 4.9 5 minutes after rated voltage	er the		
ANIA	tan δ	0.1 or le	ess			0.1	or less	i		0.3	or le	SS			0.2	2 or le	SS			~1.0 5~68		0.04 o 0.06 o		Paragraph 4.8	3, 120 Hz
	ESR	LP case 200m Ω ,500m Ω <sup>MA1</sup> LA case 200m Ω ,500m Ω <sup>MA1</sup>				_			_	_					_			_	_			-			
	Surge withstanding voltage	LC	Spe valu 300%	cified ie or le	initial ess Specified	tan	val	20% or ecified i ue or le .1CV or	initial ess	△C tan LC	δ 5 V	±20% Specifi value c Specifi value c	ed init or less ed init	tial s tial	∆( tar LC	nδ S v	Specifi alue c	ed initial	∆( tar LC	ıδ	±5% Specifi value o Specifi value o	ied ini or less ied ini	tial S	Paragraph 4.2	26
	Temperature characteristics	Spec initial $^{C(C)}$ — tan $\delta$ 0.1 liteston table or less LC Refe stanc prod tab	er to dard luct ble	-55 -20~0% 0.14	1CV or 30μ A or less	△C/C tan δ Valuestom table or less LC	Refer to standard product table		 1CV or 30μ A or less	△C/C tan ð Valuestour table or less LC	Specified initial value 0.30 Refer to standard product table	-20~+20% 0.60	0.30 1000% or less specified initial value or less	initial value or less	△C/C tan & Valueston table or less LC	Refer to standard product table	-20~0% 0.3	85         12           0~+20%         0~+2           0.2         0.           1000% or 1250%         1250%           initial value initial value initial value or less or lear or	1% △C/C 3 tan δ Valueston table or less or less inted LC lue	0.04 0.06 0.01Cl or 0.5μA c less	-10~0% 0.04 0.06	or 5μ A or less	0.05 0.07 0.125CV or 6.25µA or less	Paragraph 4.2	
	Solder heat resistance		Spe valu	cified ie or le	initial ess	tan	ιδ Sp val	20% or ecified i ue or le	initial ess	tan	δ 5	±20% Specifi /alue c	ed ini or less	tial	tar	ηδ S v	Specifi alue c		tar	ıδ	±5% Specif value	ied ini or less	tial	Solder Dip LM,J,LP,P,LA, UA,A,UB,B case 10±1 sec.	260±5℃ C,E,F case 5±0.5 sec.
			initial	value c				.1CV or		LC	١	Specifi /alue c	or less	\$	LC	v	alue c		LC		Specif value o	or less	6	Reflow 260°C	10±1 sec.
	Moisture	$\triangle C/C$ tan $\delta$			)% or less	I 1	C/C +30 1δ Sp		% or less	△C tan		±20%  50% or						or less less Specifi			±5% Specif			Paragraph 4.2	
	resistance		valu	ie or le	ess		val	ue or le	ess		i	nitial valı	ue or lė	SS		ir	nitial valı	ue or less			value o	or less	6	90 ~ 95%RH,	
	no load		initial	value c			initia	al value o			\	Specifi /alue c	or less	6	LC	v	alue c		LC		Specif	or less	\$		000hours)
	High-temperature	$\triangle C/C$ tan $\delta$		0% or cified		△( tan	C/C ±2 nδ Sp	20% or ecified		tan	δ	±20% Specifi	ed ini <sup>.</sup>	tial	∆( tar			or less ed initial	tar	ıδ	±10% Specif	ied ini	tial	Paragraph 4.2 The rated volta	age is
	load		300%		Specified	LC	300	ue or le % or less al value o	Specified	LC	2	value c 200% or	less Sp	ecified	LC	; 2	00% or	or less less Specifi	ed LC	;	válue ( 125% or initial val	less Sp	ecified	applied for 200 (TMCH:Derated vol THC:Derated vol	ltage in 125°C,
		△C/C		l value o 0% or			$C/C \pm 2$			$\triangle 0$		nitial val ±20%			$\triangle$			ue or less or less	$\triangle$		±5% o		:55	Leave at -55°C, norma	l temperature,
	Thermal shock	tan ∂	Spe valu	cified ie or le	initial ess	tan		ecified i ue or le		tan	δ	Specifi value c	ed init	tial	tar		Specifi alue c	ed initial or less	tar		Specifi value o			125°C, and normal ten 30 min., 3 min., 30 mir Repeat this operation	n., and 3 min.
		LC 300% or less Specified LC ≦0.1CV or ≦0.3CV LC		Specifi value c	ed init	tial	LC	5		ed initial	LC	:	Specifi value d	ied ini	tial	TMCS,TMCT>	(:20 cycles								
	Maistura registance																	±10%			40℃, humidity 9				
	Moisture resistance			_				_				_					_				150% or initial va	lue or le	SS	for 500 hours.	e is applied
	load															LC 125% or less Specified initial value or less			(TMCH,THC:65°C)						
	Failure rate	1%/1	000ł	nrs		1%	%∕1000	)hrs		The	e sam	ie as sl	nown a	at left	Th	e sam	e as sl	nown at le	ft Th	e san	ne as s	hown	at left	t left 85°C. The rated voltage is applied (through a protective resistor of 1 Ω/V)	

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# TANTALUM ELECTROLYTIC CAPACITORS

				TMCI	М				TMC	P				TMC	J				TMCF	7		Test conditions JIS C5101-1:1998	
Specifications Table	-55°	C~-	+12	5℃			Tł	ne sam	e as sl	hown a	t left	Tł	ne sam	ne as sl	nown a	at left	Th	ne sam	e as sl	nown a	t left		
Rated voltage	DC	2.5~	·35\	V			DC	2.5~2	5V			DC	2.5~3	5V			DC	5.3~3	5V			85°C	
Surge voltage	DC	3.2~	45	V			DC3.2~32V						DC3.2~45V					3~45V	,			85℃	
Derated voltage	DC.	1.6~	22	V			DC	1.6~1	6V			DC1.6~22V					DC4	4∼22V	1			125℃ (TNC:105℃, THC:150℃)	
Capacitance	0.47	7~47	بر 70	٤F			0.1~47 μF						0.1~220 μF					~330 µ	F				
Capacitance tolerance	±1	0% o	or 20	)%			The same as shown at lef					The same as shown at left					The same as shown at left					Paragraph 4.7, 120 Hz	
Leakage current	t Refer to standard product tab						Refer to standard product table					Ref	er to st	andard	produc	ct table	0.01	1CV or	less			Paragraph 4.9, in 5 minutes after the rated voltage is applied.	
tan∂	Refer to standard product tabl						Refer to standard product table Refe						er to st	standard product table				~68 ~150	(	0.06 or 0.08 or 0.1 or l 0.15 or	less ess	Paragraph 4.8, 120 Hz	
Surge withstanding voltage	△C tan LC		Spe	cified ir	r less nitial value nitial value		△C tan LC	δS		or less nitial value nitial value		∆( tan LC	d	土5% c Specified Specified	initial valu		Tŀ	ne sam	e as sł	nown a	t left	Paragraph 4.26	
Temperature characteristics	△C/C tan <i>δ</i> Valueshown table or less LC	Specifi initial va 0.04 0.06 0.08 0.12 0.12 0.12 0.12 0.12 0.12 0.12 0.12	4	-55 10~0% 0.09 0.1 0.12 0.14 0.16 0.20 0.34 0.36 0.60		125 0~+12% 0.09 0.1 0.12 0.14 0.16 0.20 0.22 0.24 0.40 r 1250% or d less specified intid value or less	△C/C tan ∂ Value shown table or less LC	Specified initial value 0.06 0.08 0.1 0.12 0.20 0.30 Refer to standard product table	-55 -20~0% 0.1 0.12 0.14 0.16 0.24 0.60 -	85 0~+20% 0.08 0.1 0.12 0.14 0.22 0.30 1000% or less specified initial value or less		△C/C tan ∂ Value shown table or less	Specified initial value 0.04 0.06 0.08 0.1 0.12 0.18 0.20 Refer to standard product table	-10~0% 0.05 0.08 0.12 0.14 0.16 0.22 0.24 -		0.05 0.06 0.12 0.14 0.16 0.22 0.24	△C/C tan <i>δ</i> Valuestown table or less LC		-55 -10~0% 0.1 0.12 0.14 0.22 0.60 -	85 0~+10% 0.08 0.1 0.12 0.18 0.30 0.1CV	125 0~+12% 0.1 0.12 0.14 0.22 0.40 0.125CV	Paragraph 4.24	
Solder heat resistance	△C tan LC		Spe	cified i	r less nitial valu nitial valu	ie or less ie or less	△C tan LC	δS		or less nitial valu nitial valu		△C tan LC	δS	±5% o Specified i Specified i	nitial valu		△C tan LC	δSp	becified in	or less nitial value nitial value		Solder Dip         260±5°C           LM,J,LP,P,LA,         C,E,F case           UA,A,UB,B case         10±1 sec.           S±0.5 sec.         Reflow 260°C           10±1 sec.         5±0.5 sec.	
Moisture resistance no load	△C tan LC		Spe	cified i	or less nitial valu nitial valu	ie or less	△C tan LC	δ 15	0% or less Sj	or less pecified initial nitial valu			δS	±10% Specified i Specified i	nitial valu	ie or less	The same as shown at left				t left	Paragraph 4.22 40°C 90 ~ 95%RH, 500hours (TMCH,THC:85°C,85%RH, 1000hours)	
High-temperature	△C tan LC		Spe	cified i	or less nitial valu pecified initial		△C tan LC	δS	pecified i	or less nitial valu pecified initial		△C tan LC	δS	±10% Specified i 25% or less S	nitial valu		△C tan LC	δSI	pecified in	or less nitial valu nitial valu		Paragraph 4.23 85°C The rated voltage is applied for 2000 hours. (TMCH:Derated voltage in 125°C, THC:Derated voltage in 150°C)	
Thermal shock						e or less					△C tan LC	δS	±5% o specified in specified in	nitial valu							Leave at -55°C, normal temperature, 125°C, and normal temperature for 30 min., 3 min., 30 min., and 3 min. Repeat this operation 5 cycles running. TMCS,TMCTX:20 cycles TMCH,THC:1000 cycles		
Moisture resistance Ioad	△C tan LC		150%	or less Sp	or less pecified initial pecified initial	value or less														and an			
Failure rate	1%	/10	00h	irs			Tł	ne sam	e as sl	hown a	t left	Tł	ne sam	ne as s	nown a	at left	T٢	ne sam	e as sl	nown a	t left	85°C. The rated voltage is applied (through a protective resistor of 1 $\Omega$ /V).	

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# TANTALUM ELECTROLYTIC CAPACITORS

## Specifications Table

[			TMCH	4		TMCTX					THC					Test conditions JIS C5101-1:1998	
Specifications Table	-55°(	C~+1	25℃			The same as shown at left					-55℃~+150℃						
Rated voltage	DC4	~35V	,			DC10~35V					DC10~35V					85°C	
Surge voltage	DC5	i∼45V	,			DC13~45V					DC13~45V					85°C	
Derated voltage	DC2	2.5~22	2V			DC6.3~22V					DC6.3~22V					125°C (TNC:105°C, THC:150°C)	
Capacitance	0.1~100 µ F						1~68 μ F					0.33~47 μ F					
Capacitance tolerance	±10% or 20%						The same as shown at left					The same as shown at left				Paragraph 4.7, 120 Hz	
Leakage current	0.005 CV or 0.25 $\mu$ A, whichever is larger or less						0.01 CV or 0.5 $\mu$ A, whichever is larger or less					0.05 CV or 0.25 $\mu$ A, whichever is larger or less				Paragraph 4.9, in 5 minutes after the rated voltage is applied.	
tan∂	0.1~1.0 0.04 or less 1.5~100 0.06 or less △C/C ±5% or less						1.0 or less         0.04 or less           1.5~22         0.05 or less           33 or more         0.06 or less					1.0 or less 0.04 or less 1.5 or more 0.06 or less △C/C ±10% or less				Paragraph 4.8, 120 Hz	
Surge withstanding voltage	tan $\delta$ Specified initial value or less LC Specified initial value or less						The same as shown at left					$\Delta C/C \equiv 10\%$ or less tan $\delta$ Specified initial value or less LC Specified initial value or less				Paragraph 4.26	
Temperature characteristics	△C/C tan ∂ Value shown table or less LC	initial value 	-10~0% 0.04 0.06 0.08	0~+10% 0.05 0.07 0.10 0.05CV or 25µAorless	or	△C/C tan <i>δ</i> Valueshown table or less LC	initial value — 0.04 0.05 0.06 0.01CV or 0.5 µA or less	-10~0% 0.09 0.1 0.12	0~+10% 0.07 0.08 0.1 0.1CV or 5 µ A or less	0~+12% 0.09 0.1 0.12 0.125CV or 625 μA αr less	△C/C tan δ Valueshown table or less LC	initial value 0.04 0.06 0.005CV or 0.25 µA or les	-10~0% 0.04 0.06	0~+10% 0.06 0.08 0.1CV or 5μA or less	0~+20% 0.08 0.1 0.125CV or 625 μA αr less	Paragraph 4.24	
Solder heat resistance							The same as shown at left									Solder Dip         260±5℃           LM,J,LP,P,LA,         C,E,F case           UA,A,UB,B case         10±1 sec.           5±0.5 sec.         Reflow 260℃           10±1 sec.         10±1 sec.	
Moisture	$\triangle$ C/C $\pm$ 5% or less					$\triangle$ C/C ±10% or less					$\triangle$ C/C $\pm$ 10% or less					Paragraph 4.22 40°C	
resistance	tana	\$ 150	% or less Specified initial value or less			·					$\tan\delta$ 150% or less Specified initial value or less						
no load	LC 200% or less Specified initial value or					s LC Specified initial value or less					LC 200% or less Specified initial value or less				value or less	(TMCH,THC:85°C,85%RH, 1000hours)	
High-temperature Ioad						The same as shown at left					The same as shown at left					Paragraph 4.23 85℃ The rated voltage is applied for 2000 hours. (TMCH:Derated voltage in 125℃, THC:Derated voltage in 150℃)	
Thermal shock	△C, tan a LC	S Sp	土5% or less Specified initial value or less 200% or less Specified initial value or less													Leave at -55°C, normal temperature, 125°C, and normal temperature for 30 min., 3 min., 30 min., and 3 min. Repeat this operation 5 cycles running. TMCS,TMCTX:20 cycles TMCH,THC:1000 cycles	
Moisture resistance	△C tan à		$\pm 5\%$ or less 150% or less Specified initial value or less				$\triangle$ C/C $\pm$ 10% or less tan $\delta$ 150% or less Specified initial value or less					$\triangle$ C/C $\pm$ 10% or less tan $\delta$ 150% or less Specified initial value or less				40°C, humidity 90 to 95%RH The rated voltage is applied for 500 hours.	
load	LC 200% or less Specified initial value or less					LC 200% or less Specified initial value or less					LC 200% or less Specified initial value or less					(TMCH,THC:65°C)	
Failure rate	0.5%	6/100	00hrs			1%/1000hrs					0.5%/1000hrs					85°C. The rated voltage is applied (through a protective resistor of $1 \Omega/V$ ).	

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